## **INTEGRATED CIRCUITS**

## DATA SHEET



# **74LVC32A**Quad 2-input OR gate

Product specification IC24 Data Handbook

1997 Jun 30





## **Quad 2-input OR gate**

**74LVC32A** 

#### **FEATURES**

- Wide supply voltage range of 1.2 V to 3.6 V
- In accordance with JEDEC standard no. 8-1A.
- Inputs accept voltages up to 5.5 V
- CMOS low power consumption
- Direct interface with TTL levels

#### **DESCRIPTION**

The 74LVC32A is a high-performance, low-power, low-voltage Si-gate CMOS device and superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of these devices as translators in a mixed 3.3V/5V environment.

The 74LVC32A provides the 2-input OR function.

#### **QUICK REFERENCE DATA**

GND = 0 V;  $T_{amb} = 25^{\circ}C$ ;  $t_{r} = t_{f} \le 2.5 \text{ ns}$ 

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay nA, nB to nY	$C_L = 50 \text{ pF};$ $V_{CC} = 3.3 \text{ V}$	2.6	ns
C <sub>I</sub>	Input capacitance		5.0	pF
C <sub>PD</sub>	Power dissipation capacitance per gate	Notes 1 and 2	28	pF

#### NOTES:

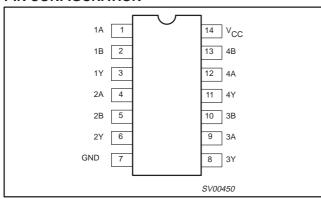
- 1.  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W)  $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$  where:  $f_i$  = input frequency in MHz;  $C_L$  = output load capacity in pF;  $f_o$  = output frequency in MHz;  $V_{CC}$  = supply voltage in V;  $\sum (C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.
- 2. The condition is  $V_I = GND$  to  $V_{CC}$ .



#### ORDERING INFORMATION

ONDERNING INI ONMATION				
PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
14-Pin Plastic SO	-40°C to +85°C	74LVC32A D	74LVC32A D	SOT108-1
14-Pin Plastic SSOP Type II	-40°C to +85°C	74LVC32A DB	74LVC32A DB	SOT337-1
14-Pin Plastic TSSOP Type I	-40°C to +85°C	74LVC32A PW	74LVC32APW DH	SOT402-1

#### **PIN CONFIGURATION**



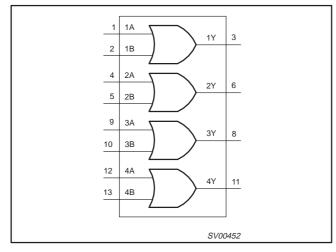
#### **PIN DESCRIPTION**

	-					
PIN NUMBER	SYMBOL	NAME AND FUNCTION				
1, 4, 9, 12	1A – 4A	Data inputs				
2, 5, 10, 13	1B – 4B	7 Data Iliputs				
3, 6, 8, 11	1Y – 4Y	Data outputs				
7	GND	Ground (0 V)				
14	Vcc	Positive supply voltage				

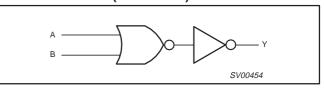
## Quad 2-input OR gate

74LVC32A

#### **LOGIC SYMBOL**



### LOGIC DIAGRAM (ONE GATE)

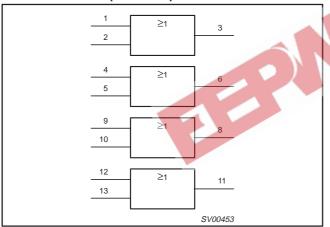


#### **FUNCTION TABLE**

INP	OUTPUTS	
nA	nY	
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н

#### NOTES:

#### LOGIC SYMBOL (IEEE/IEC)





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## Quad 2-input OR gate

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#### **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	DADAMETED	CONDITIONS	LIM	UNIT	
	PARAMETER	CONDITIONS	MIN	MAX	UNII
V <sub>CC</sub>	DC supply voltage (for max. speed performance)		2.7	3.6	V
V <sub>CC</sub>	DC supply voltage (for low-voltage applications)		1.2	3.6	V
$V_{I}$	DC input voltage range		0	5.5	V
Vo	DC output voltage range; output HIGH or LOW state		0	V <sub>CC</sub>	V
T <sub>amb</sub>	Operating ambient temperature range in free-air		-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input rise and fall times	$V_{CC} = 1.2 \text{ to } 2.7V$ $V_{CC} = 2.7 \text{ to } 3.6V$	0 0	20 10	ns/V

#### ABSOLUTE MAXIMUM RATINGS<sup>1</sup>

In accordance with the Absolute Maximum Rating System (IEC 134). Voltages are referenced to GND (ground = 0V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage	3, 35, 10	-0.5 to +6.5	V
I <sub>IK</sub>	DC input diode current	V <sub>I</sub> < 0	-50	mA
V <sub>I</sub>	DC input voltage	Note 2	-0.5 to +6.5	V
I <sub>OK</sub>	DC output diode current	$V_{O} > V_{CC}$ or $V_{O} < 0$	±50	mA
Vo	DC output voltage; output HIGH or LOW state	Note 2	-0.5 to V <sub>CC</sub> +0.5	V
I <sub>O</sub>	DC output source or sink current	$V_{O} = 0$ to $V_{CC}$	±50	mA
I <sub>GND</sub> , I <sub>CC</sub>	DC V <sub>CC</sub> or GND current		±100	mA
T <sub>stg</sub>	Storage temperature range		-65 to +150	°C
	Power dissipation per package			
P <sub>TOT</sub>	<ul><li>plastic mini-pack (SO)</li><li>plastic shrink mini-pack (SSOP and TSSOP)</li></ul>	above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	500 500	mW

#### NOTES:

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<sup>1.</sup> Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>2.</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## Quad 2-input OR gate

74LVC32A

#### **DC CHARACTERISTICS**

Over recommended operating conditions. Voltages are referenced to GND (ground = 0V).

			L			
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = -	+85°C	UNIT	
			MIN	TYP <sup>1</sup>	MAX	
V	HICH level lange valtage	V <sub>CC</sub> = 1.2V	V <sub>CC</sub>			V
V <sub>IH</sub>	HIGH level Input voltage	V <sub>CC</sub> = 2.7 to 3.6V	2.0			\ \ \
V	LOW/ lovel lanut voltage	V <sub>CC</sub> = 1.2V			GND	V
V <sub>IL</sub>	LOW level Input voltage	V <sub>CC</sub> = 2.7 to 3.6V			0.8	V
		$V_{CC} = 2.7V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = -12mA$	V <sub>CC</sub> -0.5			
	HIGH level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -100\mu\text{A}$	V <sub>CC</sub> -0.2	V <sub>CC</sub>		
V <sub>OH</sub>	nigh level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -18\text{mA}$	V <sub>CC</sub> - 0.6			]
		$V_{CC} = 3.0V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = -24$ mA	V <sub>CC</sub> -0.8			
		$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 12\text{mA}$			0.40	
V <sub>OL</sub>	LOW level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$			0.20	V
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 24\text{mA}$			0.55	
t <sub>l</sub>	Input leakage current	$V_{CC} = 3.6V; V_1 = 5.5V \text{ or GND}$		±0.1	±5	μΑ
I <sub>CC</sub>	Quiescent supply current	$V_{CC} = 3.6V; V_I = V_{CC} \text{ or GND; } I_O = 0$		0.1	10	μΑ
Δl <sub>CC</sub>	Additional quiescent supply current per input pin	$V_{CC} = 2.7 \text{V to } 3.6 \text{V}; \ V_{I} = V_{CC} - 0.6 \text{V}; \ I_{O} = 0$		5	500	μА

#### NOTE:

#### **AC CHARACTERISTICS**

GND = 0 V;  $t_r = t_f \le 2.5 \text{ ns}$ ;  $C_L = 50 \text{ pF}$ 

						LIMI	гѕ			
SYMBOL PARAMETER		WAVEFORMS	$V_{CC} = 3.3V \pm 0.3V$			\	/ <sub>CC</sub> = 2.7\	1	V <sub>CC</sub> = 1.2V	UNIT
			MIN	TYP <sup>1</sup>	MAX	MIN	TYP	MAX	TYP	
t <sub>PHL</sub> / t <sub>PLH</sub>	Propagation delay nA, nB to nY	1, 2	1.5	2.6	4.9	1.5	3.0	5.9	16	ns

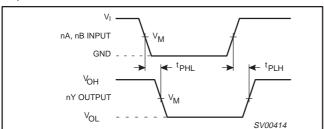
#### NOTE:

#### **AC WAVEFORMS**

 $V_{M}$  = 1.5 V at  $V_{CC}$   $\geq$  2.7 V

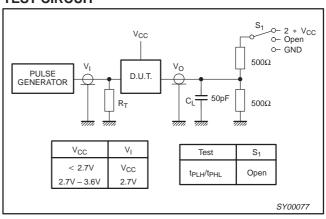
 $V_M = 0.5 \cdot V_{CC}$  at  $V_{CC} < 2.7 \text{ V}$ 

 $\rm V_{OL}$  and  $\rm V_{OH}$  are the typical output voltage drop that occur with the output load.



Waveform 1. Input (nA, nB) to output (nY) propagation delays.

#### **TEST CIRCUIT**



Waveform 2. Load circuitry for switching times.

<sup>1.</sup> All typical values are at  $V_{CC} = 3.3V$  and  $T_{amb} = 25^{\circ}C$ 

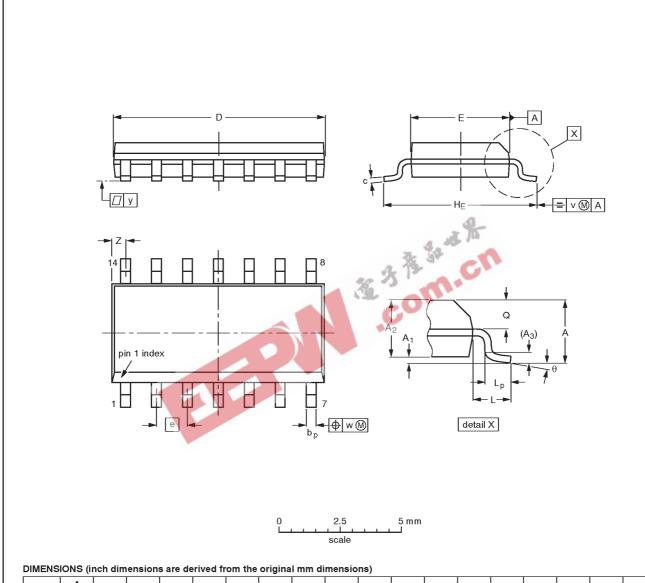
<sup>1.</sup> These typical values are at  $V_{CC}$  = 3.3V and  $T_{amb}$  = 25°C.

## Quad 2-input OR gate

74LVC32A

#### SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



Dillin	MENOITA (International are derived from the original film difference)																	
UNIT	A max.	Α1	A <sub>2</sub>	<b>A</b> <sub>3</sub>	bp	ပ	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	٧	w	у	Z <sup>(1)</sup>	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.0098 0.0039		0.01	1	0.0098 0.0075		0.16 0.15	0.050	0.24 0.23	0.041		0.028 0.024	0.01	0.01	0.004	0.028 0.012	0°

#### Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

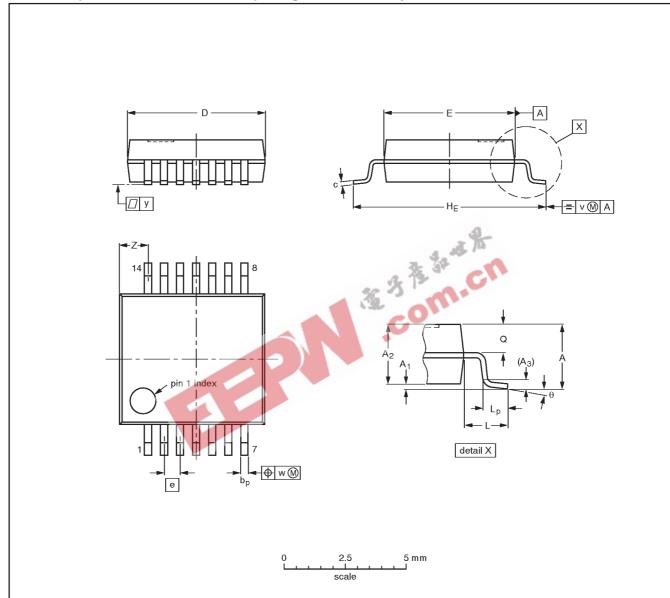
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT108-1	076E06\$	MS-012AB				<del>91 08-13</del> 95-01-23	

## Quad 2-input OR gate

74LVC32A

SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



#### DIMENSIONS (mm are the original dimensions)

						-,												
UNIT	A max.	Α <sub>1</sub>	A <sub>2</sub>	<b>A</b> <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.4 0.9	8° 0°

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

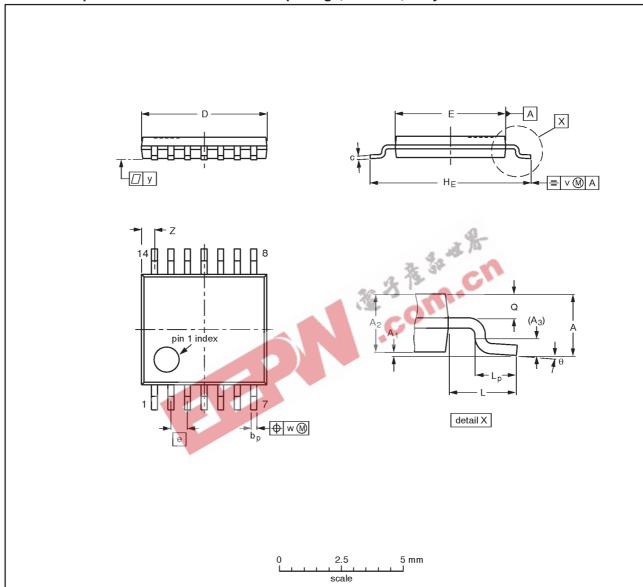
OUTLINE		EUROPEAN	ISSUE DATE			
VERSION	VERSION IEC JEDEC		EIAJ		PROJECTION	ISSUEDATE
SOT337-1		MO-150AB				<del>-95-02-04</del> 96-01-18

## Quad 2-input OR gate

74LVC32A

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



#### DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A <sub>2</sub>	А3	рb	С	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	Q	٧	w	у	Z <sup>(1)</sup>	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT402-1		MO-153				<del>-94-07-12</del> 95-04-04

## Quad 2-input OR gate

74LVC32A

#### **NOTES**



## Quad 2-input OR gate

74LVC32A



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Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.
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